# CO<sub>2</sub> reduction with water over Al<sub>2</sub>O<sub>3</sub>-supported Ga<sub>2</sub>O<sub>3</sub> photocatalysts <u>Ryota Ito,</u><sup>a\*</sup> Muneaki Yamamoto,<sup>b</sup> Akiyo ozawa, <sup>a,c</sup> Yuma Kato,<sup>a</sup> Yu Kawaguchi,<sup>a</sup> Masato Akatsuka,<sup>a</sup> Tetsuo Tanabe<sup>b</sup> and Tomoko Yoshida <sup>b,\*</sup>

<sup>a</sup> Applied Chemistry and Bioengineering Graduate School of Engineering, Osaka City University, Osaka, 558-8585, Japan.

<sup>b</sup> Advanced Research Institute for Natural Science and Technology, Osaka City University, Osaka, 558-8585, Japan. <sup>c</sup> Corporate Research Laboratories, Research & Development Division, Sakai Chemical Industry, Co., Ltd., Osaka, 590-8502, Japan.

\*corresponding author: Tomoko Yoshida: +81-6-6605-3627, tyoshida@ocarina.osaka-cu.ac.jp

**Abstract:** Al<sub>2</sub>O<sub>3</sub>-supported Ga<sub>2</sub>O<sub>3</sub> (Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub>) photocatalysts were prepared to improve the photocatalytic activity of Ga<sub>2</sub>O<sub>3</sub> for CO<sub>2</sub> reduction with water. Although the CO production activities for 5, 10 and 20 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> samples were lower than non-supported Ga<sub>2</sub>O<sub>3</sub>, the activity was significantly improved by Al<sub>2</sub>O<sub>3</sub>-supporting, in particular 40 and 60 wt% of Ga<sub>2</sub>O<sub>3</sub> loading. It was revealed that 5, 10 and 20 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> samples were single  $\alpha$ -phase Ga<sub>2</sub>O<sub>3</sub> while 40 and 60 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> samples consisted of  $\alpha$  and  $\gamma$  phases, respectively. Thus, CO production activity of the prepared samples depended on the crystalline structure of Ga<sub>2</sub>O<sub>3</sub> loaded on Al<sub>2</sub>O<sub>3</sub>.

Keywords: Ga<sub>2</sub>O<sub>3</sub> loaded Al<sub>2</sub>O<sub>3</sub>, Ga<sub>2</sub>O<sub>3</sub> structural change, photocatalytic CO<sub>2</sub> reduction with water.

## 1. Introduction

Nowadays photocatalytic reduction of CO<sub>2</sub>, which reduces greenhouse gas and creates carbon resources by using clean solar energy, has attracted much attention.  $Ga_2O_3$  is known to work as a photocatalytst for CO<sub>2</sub> reduction with water. However, its photocatalytic activity on CO<sub>2</sub> reduction remains low <sup>[1, 2]</sup>. In order to improve the photocatalytic activity of  $Ga_2O_3$ , in this study,  $Al_2O_3$  was used as support to have large surface area. We have examined photocatalytic activity of synthesized  $Al_2O_3$ -supported  $Ga_2O_3$  ( $Ga_2O_3/Al_2O_3$ ) photocatalysts having different crystalline structures for the photocatalytic CO<sub>2</sub> reduction with water and investigated the relation between the structure of  $Ga_2O_3$  and the CO production activity.

### 2. Experimental

Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> samples were prepared by impregnation of  $\gamma$ -phase Al<sub>2</sub>O<sub>3</sub> with aqueous solution of gallium nitrate followed by dry and calcination in air at 823 K for 4 h. The loading amounts of Ga<sub>2</sub>O<sub>3</sub> were 5, 10, 20, 40 and 60 wt%. Pure Al<sub>2</sub>O<sub>3</sub> and non-supported Ga<sub>2</sub>O<sub>3</sub> samples (referred as 0 and 100 wt%, respectively) were also prepared in the similar procedure. The photocatalytic CO<sub>2</sub> reduction with H<sub>2</sub>O was carried out for all prepared samples. The synthesized sample (0.1 g) was dispersed in an aqueous solution of NaHCO<sub>3</sub> (0.1M) in the fixed-bed flow reactor cell under CO<sub>2</sub> gas with a flow rate at 3.0 mL/min and irradiated by UV-light (Xe lamp). The reaction products (CO, H<sub>2</sub> and O<sub>2</sub>) were analyzed with gas chromatography. The samples were characterized with XRD and Ga K-edge EXAFS.

#### 3. Results and discussion

Fig.1 compares production rates of CO and CO selectivity for all synthesized  $Ga_2O_3/Al_2O_3$ . Although all  $Ga_2O_3/Al_2O_3$  except non-supported one showed the photocatalytic activity, both CO production rate and CO selectivity for 5, 10 and 20 wt%  $Ga_2O_3/Al_2O_3$  were lower than the others. 40 and 60 wt% of  $Ga_2O_3/Al_2O_3$  showed higher reaction rate than non-supported one. In particular, the 40 wt%  $Ga_2O_3/Al_2O_3$  showed the highest CO production rate and CO selectivity.



**Fig.1** CO production rates and CO selectivity for prepared samples after 5 h

Fig.2 compares difference XRD patterns for all prepared samples which were given by subtracting the XRD intensity of pure Al<sub>2</sub>O<sub>3</sub> from those of Al<sub>2</sub>O<sub>3</sub> supported samples. The patterns depicted that 5, 10 and 20 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> were single  $\alpha$ -phase Ga<sub>2</sub>O<sub>3</sub>, while 40 and 60 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> consisted of  $\alpha$  and  $\gamma$  phases, respectively. 100 wt% Ga<sub>2</sub>O<sub>3</sub> contained  $\beta$ -phase in addition to the  $\alpha/\gamma$ -mixed phases.

The local structures of  $Ga_2O_3/Al_2O_3$  were investigated by the EXAFS measurement of Ga K-edge spectra. The Fourier transform was performed on each EXAFS spectrum in the range from 3 Å<sup>-1</sup> to 12 Å<sup>-1</sup> and the radial structure function (RSF) was obtained as shown in Fig. 3. In the RSFs, the first peak appeared at 1-2Å is assigned to the backscattering from adjacent oxygen atoms (Ga-O bond) and the second peak around 2.7Å shows the presence of the second-neighboring gallium atoms (Ga-Ga bond) [3-5]. Considering XRD results, the RSF of 20 wt%  $Ga_2O_3/Al_2O_3$  should be corresponding to  $\alpha$ -phase  $Ga_2O_3$  in which the amplitudes of the first and second peaks are almost the same. On the other hand, in RSF of 40 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub>, the first peak is larger than the second one which is similar to that of  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>. Therefore, the  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub> phase would dominate 40 wt% Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub>. In the conference, we will discuss why the  $\alpha/\gamma$ -mixed phase Ga<sub>2</sub>O<sub>3</sub> showed high activity for CO production based on the CO<sub>2</sub> adsorption experiments and in-situ FT-IR measurements.

#### 4. Conclusions

### We have synthesized Al<sub>2</sub>O<sub>3</sub>-supported Ga<sub>2</sub>O<sub>3</sub>



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**Fig.2** Difference XRD patterns of  $Ga_2O_3/Al_2O_3$  and  $Ga_2O_3$  samples. The loading amount of  $Ga_2O_3$  is (a) 5 wt% (b) 10 wt% (c) 20 wt% (d) 40 wt% (e) 60 wt% and (f) 100 wt%.



**Fig.3** Fourier transfer Ga K-edge EXAFS spectra of (a-e) Ga<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub> samples and (g)  $\gamma$ -Ga<sub>2</sub>O<sub>3</sub>. The loading amount of Ga<sub>2</sub>O<sub>3</sub> is (a) 5 wt% (b) 10 wt% (c) 20 wt% (d) 40 wt% (e) 60 wt% and (f) 100 wt%.